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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## H7N1002LD, H7N1002LS, H7N1002LM

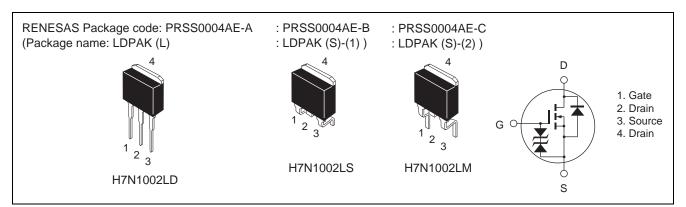
# Silicon N Channel MOS FET High Speed Power Switching

REJ03G1131-0800 Rev.8.00 Nov 13, 2009

#### **Features**

- Low on-resistance  $R_{DS (on)} = 8 \text{ m}\Omega \text{ typ.}$
- Low drive current
- Available for 4.5 V gate drive

#### **Outline**



#### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	100	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	75	Α
Drain peak current	I <sub>D (pulse)</sub> Note 1	300	Α
Body to drain diode reverse drain current	I <sub>DR</sub>	75	Α
Avalanche current	I <sub>AP</sub> Note 3	50	Α
Avalanche energy	E <sub>AR</sub> Note 3	166	mJ
Channel dissipation	Pch Note 2	100	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

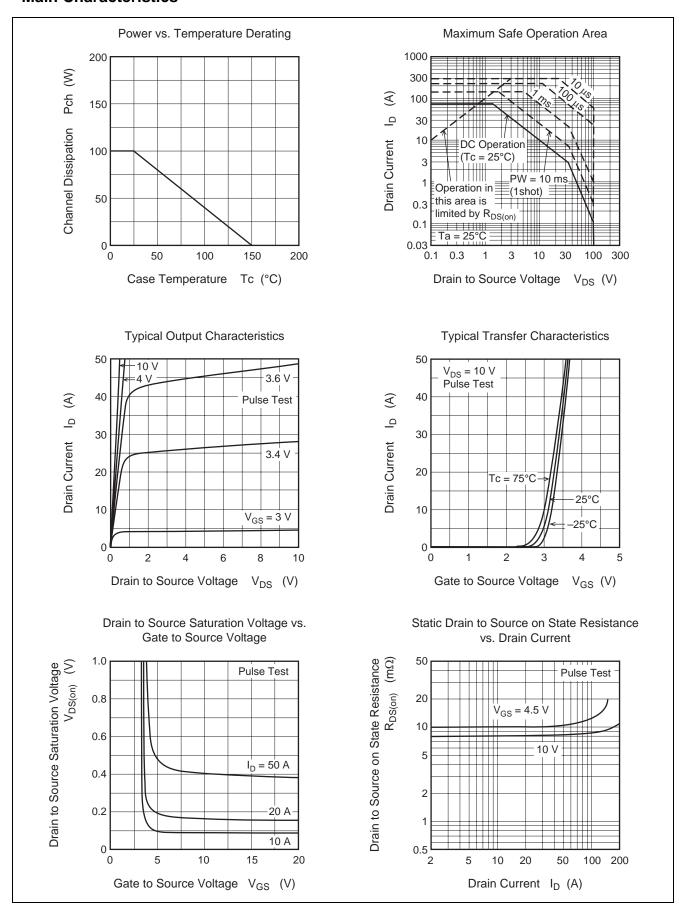
#### **Electrical Characteristics**

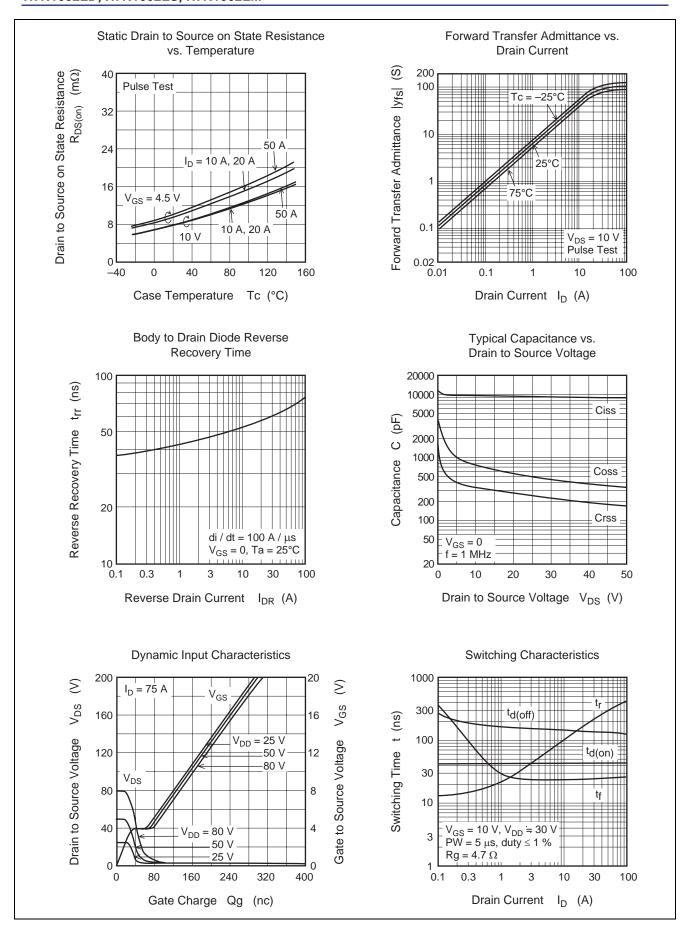
 $(Ta = 25^{\circ}C)$ 

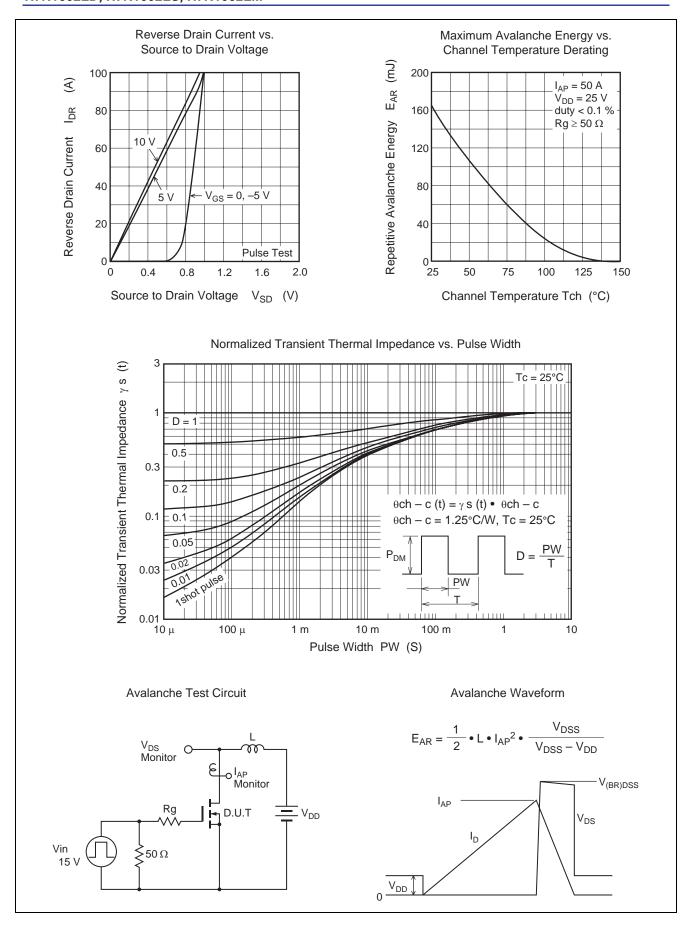
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR) DSS</sub>	100	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V <sub>(BR) GSS</sub>	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	10	μΑ	$V_{DS} = 100 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	1.5	_	2.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$
Static drain to source on state	R <sub>DS (on)</sub>	_	8	10	mΩ	$I_D = 37.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$
resistance		_	10	15	mΩ	$I_D = 37.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y <sub>fs</sub>	57	95	_	S	$I_D = 37.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	9700	_	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	_	740	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	330	_	pF	f = 1 MHz
Total gate charge	Qg	_	155	_	nC	V <sub>DD</sub> = 50 V
Gate to source charge	Qgs	_	35	_	nC	V <sub>GS</sub> = 10 V
Gate to drain charge	Qgd	_	33	_	nC	I <sub>D</sub> = 75 A
Turn-on delay time	t <sub>d (on)</sub>	_	43	_	ns	$V_{GS} = 10 \text{ V}, I_D = 37.5 \text{ A}$
Rise time	t <sub>r</sub>	_	245	_	ns	$R_L = 0.8 \Omega$
Turn-off delay time	t <sub>d (off)</sub>	_	130	_	ns	$Rg = 4.7 \Omega$
Fall time	t <sub>f</sub>	_	25	_	ns	
Body to drain diode forward voltage	$V_{DF}$	_	0.93	_	V	I <sub>F</sub> = 75 A, V <sub>GS</sub> = 0
Body to drain diode reverse recovery	t <sub>rr</sub>	_	70	_	ns	I <sub>F</sub> = 75 A, V <sub>GS</sub> = 0
time						$di_F/dt = 100 A/\mu s$

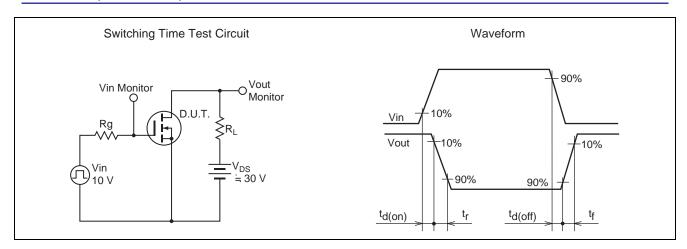
Note: 4. Pulse test

#### **Main Characteristics**

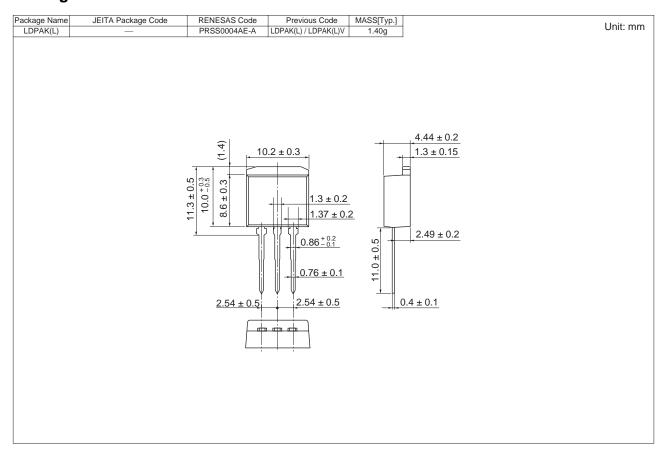


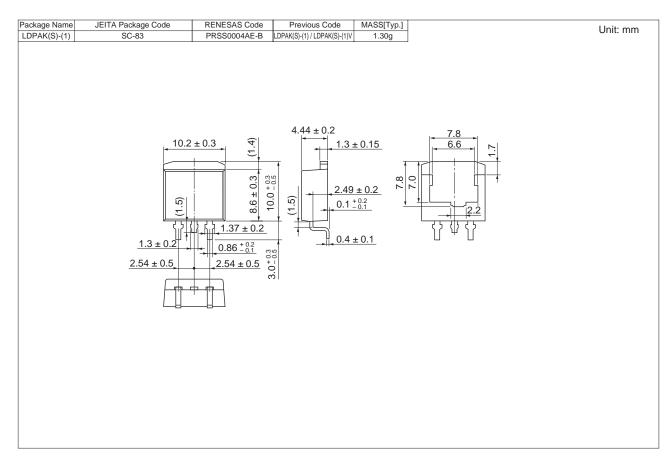


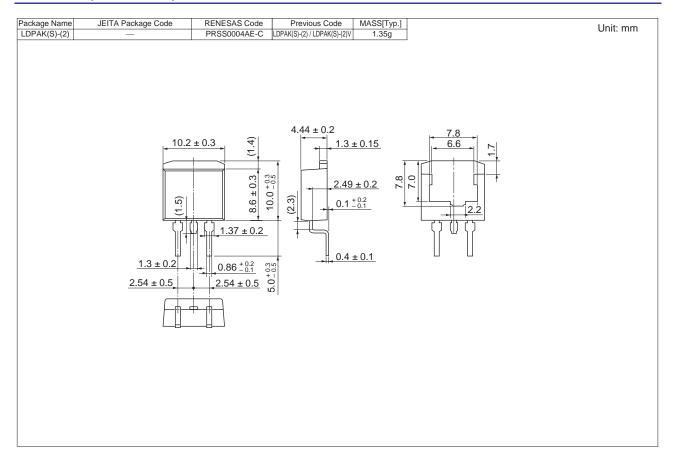




#### **Package Dimensions**







### **Ordering Information**

Part Name	Quantity	Shipping Container	
H7N1002LD-E	500 pcs	Box (Conductive Sack)	
H7N1002LSTL-E	1000 pcs	Taping	
H7N1002LMTL-E	1000 pcs	Taping	

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